# NSN 5962-01-133-6469

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# **Body Length:**

Between 1.180 inches and 1.220 inches

# Body Width:

Between 0.580 inches and 0.610 inches

# **Body Height:**

Between 0.080 inches and 0.120 inches

# Maximum Power Dissipation Rating:

1.02 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and programmable and schottky and w/active pull-up

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

## **Case Outline Source And Designator:**

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

output

# Memory Device Type:

Rom

## Memory Capacity:

Unknown

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

